



M T B F

(E I A J R C R - 9 1 0 2)

Model	PBA100F-12
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No.	P a r t s		Q' ty of Device	Failure rate [10 ⁻⁶ /H]	Reference
1	I C	Monolithic	3	0.1060	
2		Hybrid	0	0.0000	
3	Transistors		5	0.2992	
4	Diodes		21	0.4255	
5	LED•Optocouplers		3	0.1412	
6	Resistors		107	0.4687	
7	Capacitors		38	0.4656	
8	Transformer•Choke Coil		10	0.1265	
9	Connectors		580	0.3119	
10	Others		3	0.0460	
Total Failure Rate [10 ⁻⁶ /H]				2.3906	

M T B F	[H]	419,000
Ambient Temperature	[℃]	—
Load Factor	[%]	—